Supporting Information for Magnetic proximity effect in biphenylene monolayer from first-principles

Diego López-Alcalá^a and José J. Baldoví.^{a,*}

^aInstituto de Ciencia Molecular, Universitat de València, Catedrático José Beltrán 2, 46980 Paterna, Spain.



Figure S1: Effect of Hubbard U in dominant magnetic exchange coupling J_{ot} (blue) and in electronic band gap of bulk-like YIG atoms (red).



Figure S2: K-point mesh energy convergence.

Magnetic order	Energy (meV)
AFM	0
FM	2.091
Closed - shell	2.090

Table S1: Calculated energy of the possible magnetic configurations of a free standing BPN monolayer.

We computed the charge transfer in the BPN/YIG system using various methods, as summarized in Table S2. The direction of charge transfer is consistent across the results obtained from Bader, Hirshfeld, and Voronoi analyses. Among these, we use the quantitative results from the Bader method for our conclusions, as it provides a more detailed description of the interface, accounting for its intricate topology.¹

Table S2: Calculated charge transfer in BPN/YIG with different methods.

	Bader	Hidsfrield	Voronoi
Charge transfer (<i>e</i> /f.u.)	0.58	1.15	1.63



Figure S3: BPN spin density. Isosurface 0.0001 e/Å³.



Figure S4: a) Calculated Magnetic exchange couplings (J) in the bulk-like Fe atoms in YIG. b) Summary of J in YIG obtained in different works. Obtained from O. I. Gorbatov *et al.*, *Phys. Rev. B*, **104**, 174401 (2021).

Without BPN	With BPN	Variation (%)
-9.02	-9.46	4.88
-9.08	-9.47	4.23
-9.02	-9.39	4.14
-8.42	-8.62	2.38
-8.34	-8.54	2.39
-8.41	-8.65	2.95
-10.15	-10.29	1.30
-10.41	-10.51	0.95
-9.88	-9.94	0.57
-9.57	-9.72	1.52
-9.43	-9.59	1.67
-9.80	-9.93	1.35
-8.46	-8.59	1.50
-8.54	-8.67	1.58
-9.70	-9.85	1.52
-9.69	-9.90	2.11
-8.48	-8.61	1.59
-9.71	-9.87	1.70

Table S3: First neighbor magnetic exchange interaction (J_{ot}) in meV for bulk-like Fe^O atoms.



Figure S5: Charge density difference after BPN deposition on (111) YIG surface at $d - d_0 = 0.9$ Å. Color code: blue (yellow) regions represent charge depletion (accumulation). Inset shows separately the charge depletion and accumulation, respectively. Isosurface is set to 0.001 *e*/Å³.